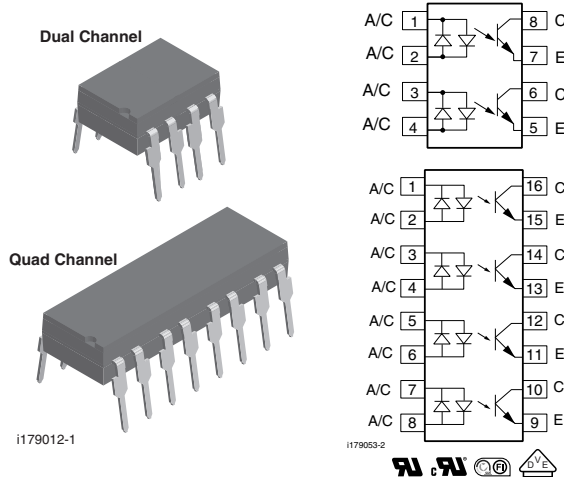


## Optocoupler, Phototransistor Output, AC Input (Dual, Quad Channel)



### FEATURES

- Identical channel to channel footprint
- ILD620 crosses to TLP620-2
- ILQ620 crosses to TLP620-4
- High collector emitter voltage,  $BV_{CEO} = 70\text{ V}$
- Dual and quad packages feature:
  - Reduced board space
  - Lower pin and parts count
  - Better channel to channel CTR match
  - Improved common mode rejection
- Isolation test voltage 5300  $V_{RMS}$
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC



**RoHS**  
COMPLIANT

### DESCRIPTION

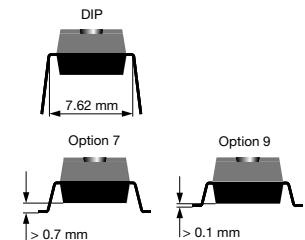
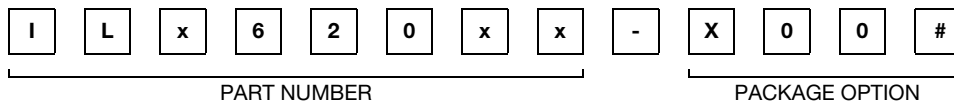
The ILD620, ILQ620 and ILD620GB, ILQ620GB are multi-channel input phototransistor optocouplers that use inverse parallel GaAs IRLLED emitter and high gain NPN silicon phototransistors per channel. These devices are constructed using over/under leadframe optical coupling and double molded insulation resulting in a withstand test voltage of 5300  $V_{RMS}$ .

The LED parameters and the linear CTR characteristics make these devices well suited for AC voltage detection. The ILD620GB, ILQ620GB with its low  $I_F$  guaranteed  $CTR_{CESat}$  minimizes power dissipation of the  $A_C$  voltage detection network that is placed in series with the LEDs. Eliminating the phototransistor base connection provides added electrical noise immunity from the transients found in many industrial control environments.

### AGENCY APPROVALS

- UL1577, file no. E52744 system code H, double protection
- CSA 22.2 bulletin 5A, double protection
- DIN EN 60747-5-2 (VDE 0884)  
DIN EN 60747-5-5 pending
- FIMKO

### ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)	
	$\pm 5\text{ mA}$	
<b>UL, cUL, VDE, FIMKO</b>	<b>50 to 600</b>	<b>100 to 600</b>
DIP-8	ILD620	ILD620GB
DIP-16	ILQ620	ILQ620GB
SMD-8 (option 7)	ILD620-X007	-
SMD-8 (option 9)	ILD620-X009	ILD620GB-X009
SMD-16 (option 9)	ILQ620-X009	ILQ620GB-X009

# ILD620, ILD620GB, ILQ620, ILQ620GB



Vishay Semiconductors Optocoupler, Phototransistor Output,  
AC Input (Dual, Quad Channel)

ABSOLUTE MAXIMUM RATINGS <sup>(1)</sup> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)					
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
<b>INPUT</b>					
Forward current			$I_F$	$\pm 60$	mA
Surge current			$I_{FSM}$	$\pm 1.5$	A
Power dissipation			$P_{diss}$	100	mW
Derate linearly from 25 °C				1.3	mW/°C
<b>OUTPUT</b>					
Collector emitter breakdown voltage			$BV_{CEO}$	70	V
Collector current			$I_C$	50	mA
	$t < 1\text{ s}$		$I_C$	100	mA
Power dissipation			$P_{diss}$	150	mW
Derate from 25 °C				2	mW/°C
<b>COUPLER</b>					
Isolation test voltage	$t = 1\text{ s}$		$V_{ISO}$	5300	$V_{RMS}$
Isolation voltage			$V_{IORM}$	890	$V_P$
Total power dissipation			$P_{tot}$	250	mW
Package dissipation		ILD620		400	mW
		ILD620GB		400	mW
Derate from 25 °C				5.33	mW/°C
Package dissipation		ILQ620		500	mW
		ILQ620GB		500	mW
Derate from 25 °C				6.67	mW/°C
Creepage distance				$\geq 7$	mm
Clearance distance				$\geq 7$	mm
Isolation resistance	$V_{IO} = 500\text{ V}, T_{amb} = 25\text{ }^{\circ}\text{C}$		$R_{IO}$	$\geq 10^{12}$	$\Omega$
	$V_{IO} = 500\text{ V}, T_{amb} = 100\text{ }^{\circ}\text{C}$		$R_{IO}$	$\geq 10^{11}$	$\Omega$
Storage temperature			$T_{stg}$	- 55 to + 150	°C
Operating temperature			$T_{amb}$	- 55 to + 100	°C
Junction temperature			$T_j$	100	°C
Soldering temperature <sup>(2)</sup>	2 mm from case bottom		$T_{sld}$	260	°C

## Notes

- (1) Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- (2) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>							
Forward voltage	$I_F = \pm 10\text{ mA}$		$V_F$	1	1.15	1.3	V
Forward current	$V_R = \pm 0.7\text{ V}$		$I_F$		2.5	20	$\mu\text{A}$
Capacitance	$V_F = 0\text{ V}, f = 1\text{ MHz}$		$C_O$		25		pF
Thermal resistance, junction to lead			$R_{thJL}$		750		K/W
<b>OUTPUT</b>							
Collector emitter capacitance	$V_{CE} = 5\text{ V}, f = 1\text{ MHz}$		$C_{CE}$		6.8		pF
Collector emitter leakage current	$V_{CE} = 24\text{ V}$		$I_{CEO}$		10	100	nA
	$T_A = 85\text{ }^{\circ}\text{C}, V_{CE} = 24\text{ V}$		$I_{CEO}$		2	50	$\mu\text{A}$
Thermal resistance, junction to lead			$R_{thJL}$		500		K/W



# ILD620, ILD620GB, ILQ620, ILQ620GB

Optocoupler, Phototransistor Output, Vishay Semiconductors  
AC Input (Dual, Quad Channel)

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>COUPLER</b>							
Off-state collector current	$V_F = \pm 0.7\text{ V}$ , $V_{CE} = 24\text{ V}$		$I_{CEoff}$		1	10	$\mu\text{A}$
Collector emitter saturation voltage	$I_F = \pm 8\text{ mA}$ , $I_{CE} = 2.4\text{ mA}$	ILD620	$V_{CEsat}$			0.4	V
		ILQ620	$V_{CEsat}$			0.4	V
	$I_F = \pm 1\text{ mA}$ , $I_{CE} = 0.2\text{ mA}$	ILD620GB	$V_{CEsat}$			0.4	V
		ILQ620GB	$V_{CEsat}$			0.4	V

**Note**

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

<b>CURRENT TRANSFER RATIO</b>							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Channel/channel CTR match	$I_F = \pm 5\text{ mA}$ , $V_{CE} = 5\text{ V}$		CTR <sub>X</sub> /CTR <sub>Y</sub>	1 to 1		3 to 1	
CTR symmetry	$I_{CE} (I_F = -5\text{ mA})/I_{CE} (I_F = +5\text{ mA})$		$I_{CE(RATIO)}$	0.5		2	
Current transfer ratio (collector emitter saturated)	$I_F = \pm 1\text{ mA}$ , $V_{CE} = 0.4\text{ V}$	ILD620	CTR <sub>CEsat</sub>		60		%
		ILQ620	CTR <sub>CEsat</sub>		60		%
Current transfer ratio (collector emitter)	$I_F = \pm 5\text{ mA}$ , $V_{CE} = 5\text{ V}$	ILD620	CTR <sub>CE</sub>	50	80	600	%
		ILQ620	CTR <sub>CE</sub>	50	80	600	%
Current transfer ratio (collector emitter saturated)	$I_F = \pm 1\text{ mA}$ , $V_{CE} = 0.4\text{ V}$	ILD620GB	CTR <sub>CEsat</sub>	30			%
		ILQ620GB	CTR <sub>CEsat</sub>	30			%
Current transfer ratio (collector emitter)	$I_F = \pm 5\text{ mA}$ , $V_{CE} = 5\text{ V}$	ILD620GB	CTR <sub>CE</sub>	100	200	600	%
		ILQ620GB	CTR <sub>CE</sub>	100	200	600	%

<b>MAXIMUM SAFETY RATINGS</b>							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
<b>INPUT</b>							
Forward current		$I_F$			275	mA	
<b>OUTPUT</b>							
Power dissipation		$P_{diss}$			400	mW	
<b>COUPLER</b>							
Rated impulse voltage		$V_{IOTM}$			10	kV	
Safety temperature		$T_{si}$			175	$^{\circ}\text{C}$	

**Note**

- According to DIN EN 60747-5-2 (VDE 0884) (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

<b>INSULATION RATED PARAMETERS</b>							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Partial discharge test voltage - routine test	100 %, $t_{test} = 1\text{ s}$	$V_{pd}$	1.669			kV	
Partial discharge test voltage - lot test (sample test)	$t_{Tr} = 60\text{ s}$ , $t_{test} = 10\text{ s}$ , (see figure 2)	$V_{IOTM}$	10			kV	
		$V_{pd}$	1.424			kV	
Insulation resistance	$V_{IO} = 500\text{ V}$	$R_{IO}$	$10^{12}$			$\Omega$	
	$V_{IO} = 500\text{ V}$ , $T_{amb} = 100\text{ }^{\circ}\text{C}$	$R_{IO}$	$10^{11}$			$\Omega$	
	$V_{IO} = 500\text{ V}$ , $T_{amb} = 150\text{ }^{\circ}\text{C}$ (construction test only)	$R_{IO}$	$10^9$			$\Omega$	

# ILD620, ILD620GB, ILQ620, ILQ620GB



Vishay Semiconductors Optocoupler, Phototransistor Output,  
AC Input (Dual, Quad Channel)

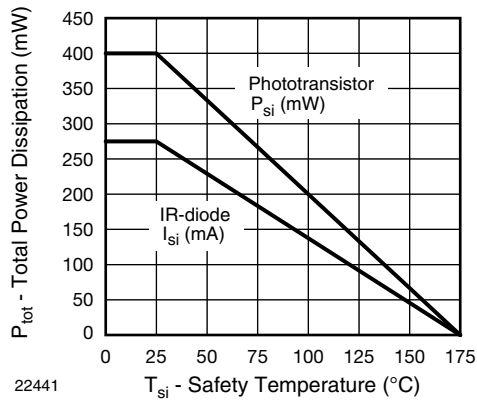


Fig. 1 - Derating Diagram

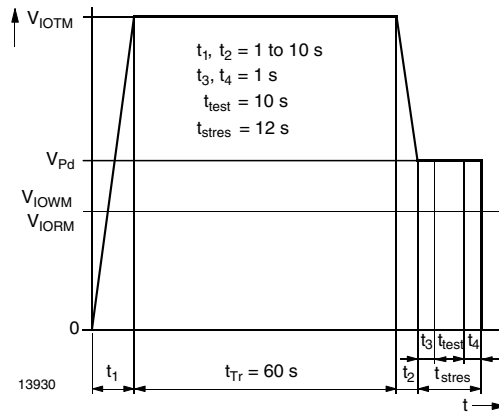


Fig. 2 - Test Pulse Diagram for Sample Test According to  
DIN EN 60747-5-2 (VDE 0884); IEC 60747-5-5

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>NON-SATURATED</b>						
On time	$I_F = \pm 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega, 50 \% \text{ of } V_{PP}$	$t_{on}$		3		$\mu\text{s}$
Rise time	$I_F = \pm 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega, 50 \% \text{ of } V_{PP}$	$t_r$		20		$\mu\text{s}$
Off time	$I_F = \pm 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega, 50 \% \text{ of } V_{PP}$	$t_{off}$		2.3		$\mu\text{s}$
Fall time	$I_F = \pm 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega, 50 \% \text{ of } V_{PP}$	$t_f$		2		$\mu\text{s}$
Propagation H - L	$I_F = \pm 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega, 50 \% \text{ of } V_{PP}$	$t_{PHL}$		1.1		$\mu\text{s}$
Propagation L - H	$I_F = \pm 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 75 \Omega, 50 \% \text{ of } V_{PP}$	$t_{PLH}$		2.5		$\mu\text{s}$
<b>SATURATED</b>						
On time	$I_F = \pm 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega, V_{TH} = 1.5 \text{ V},$	$t_{on}$		4.3		$\mu\text{s}$
Rise time	$I_F = \pm 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega, V_{TH} = 1.5 \text{ V},$	$t_r$		2.8		$\mu\text{s}$
Off time	$I_F = \pm 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega, V_{TH} = 1.5 \text{ V},$	$t_{off}$		2.5		$\mu\text{s}$
Fall time	$I_F = \pm 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega, V_{TH} = 1.5 \text{ V},$	$t_f$		11		$\mu\text{s}$
Propagation H - L	$I_F = \pm 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega, V_{TH} = 1.5 \text{ V},$	$t_{PHL}$		2.6		$\mu\text{s}$
Propagation L - H	$I_F = \pm 10 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega, V_{TH} = 1.5 \text{ V},$	$t_{PLH}$		7.2		$\mu\text{s}$

**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

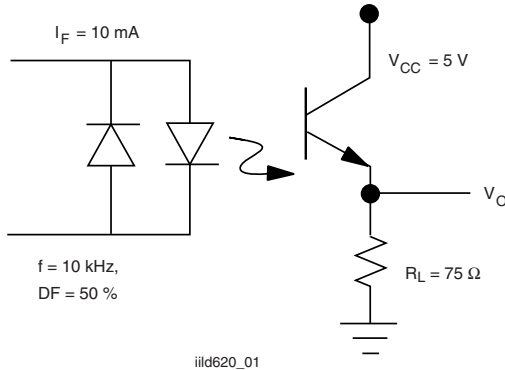


Fig. 3 - Non-Saturated Switching Timing

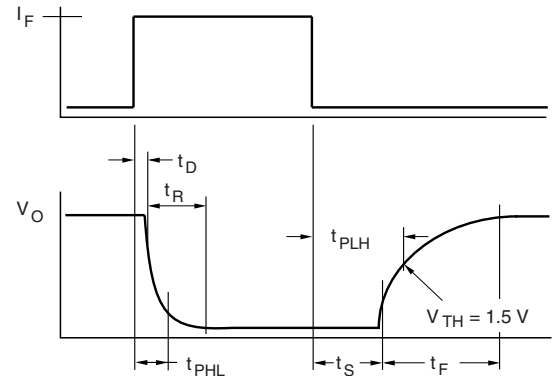


Fig. 6 - Saturated Switching Timing

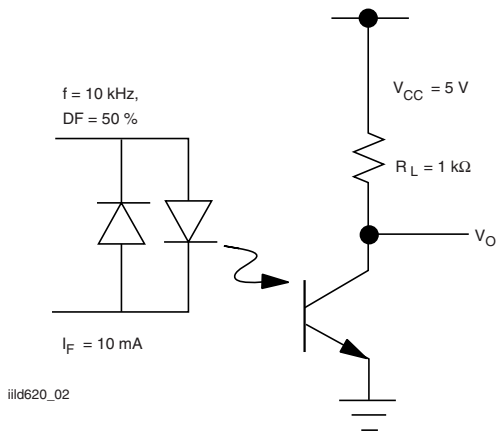


Fig. 4 - Saturated Switching Timing

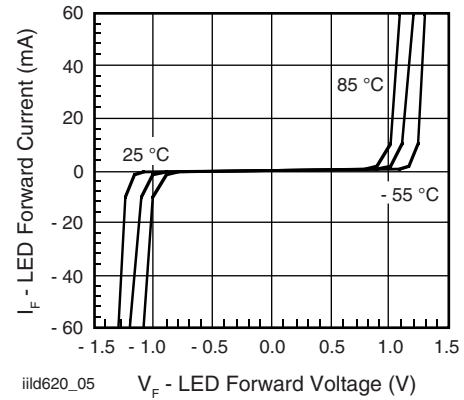


Fig. 7 - LED Forward Current vs. Forward Voltage

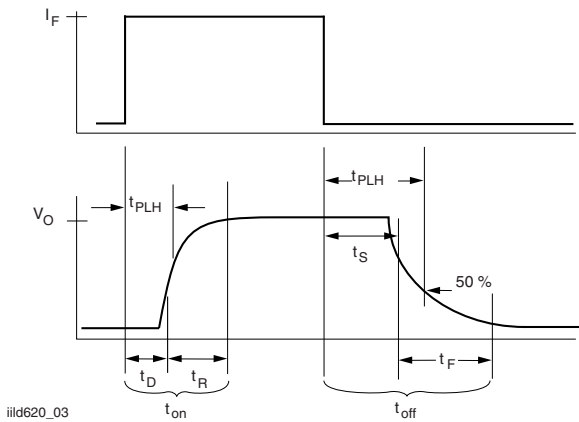


Fig. 5 - Non-Saturated Switching Timing

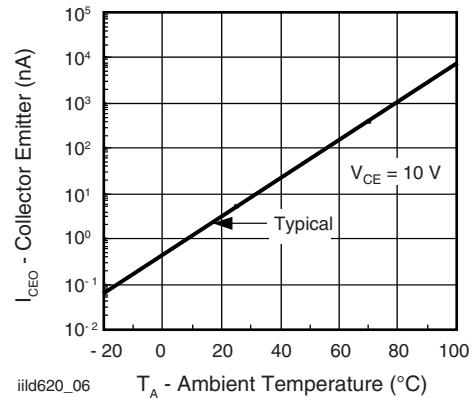


Fig. 8 - Collector Emitter Leakage vs. Temperature

# ILD620, ILD620GB, ILQ620, ILQ620GB



Vishay Semiconductors Optocoupler, Phototransistor Output,  
AC Input (Dual, Quad Channel)

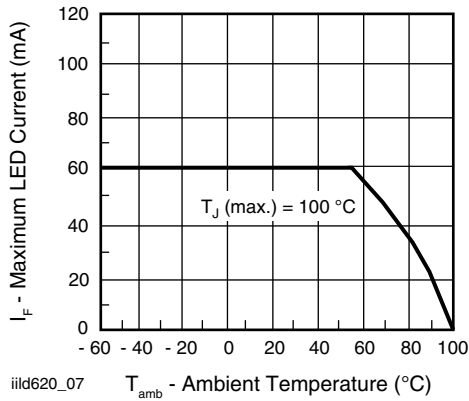


Fig. 9 - Maximum LED Current vs. Ambient Temperature

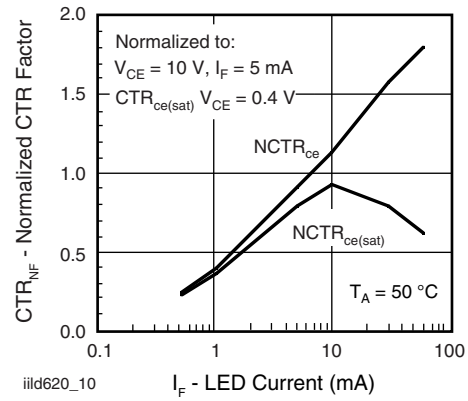


Fig. 12 - Normalization Factor for Non-Saturated and Saturated CTR vs.  $I_F$

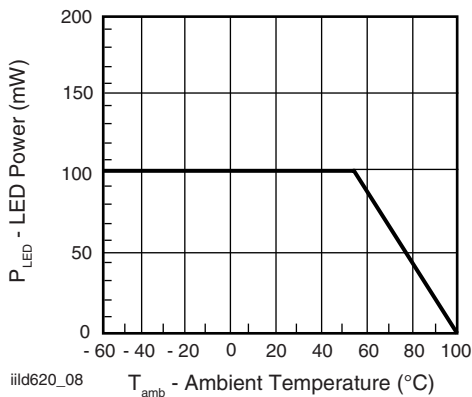


Fig. 10 - Maximum LED Power Dissipation

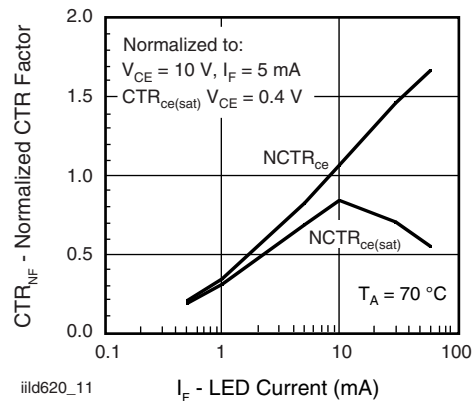


Fig. 13 - Normalization Factor for Non-Saturated and Saturated CTR vs.  $I_F$

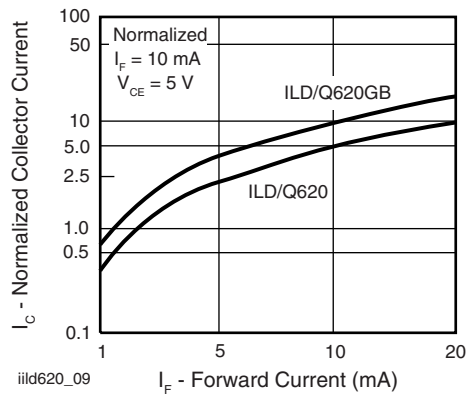


Fig. 11 - Collector Current vs. Diode Forward Current

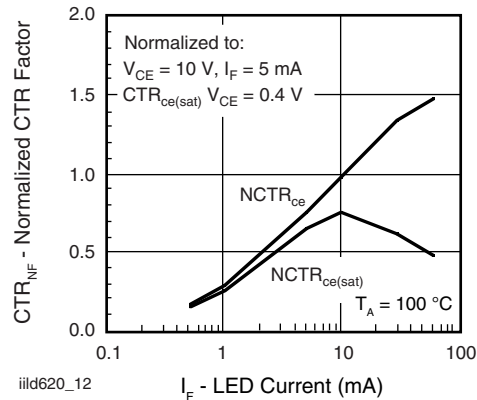


Fig. 14 - Normalization Factor for Non-Saturated and Saturated CTR vs.  $I_F$

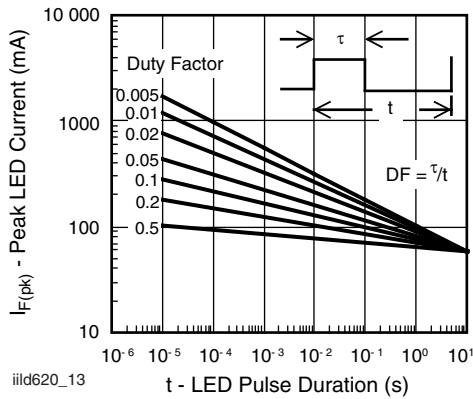


Fig. 15 - Peak LED Current vs. Pulse Duration,  $\tau$

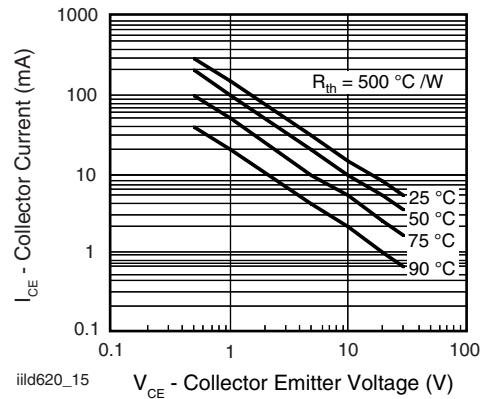


Fig. 17 - Maximum Collector Current vs. Collector Voltage

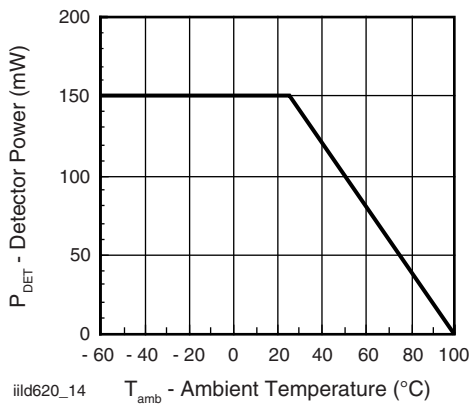
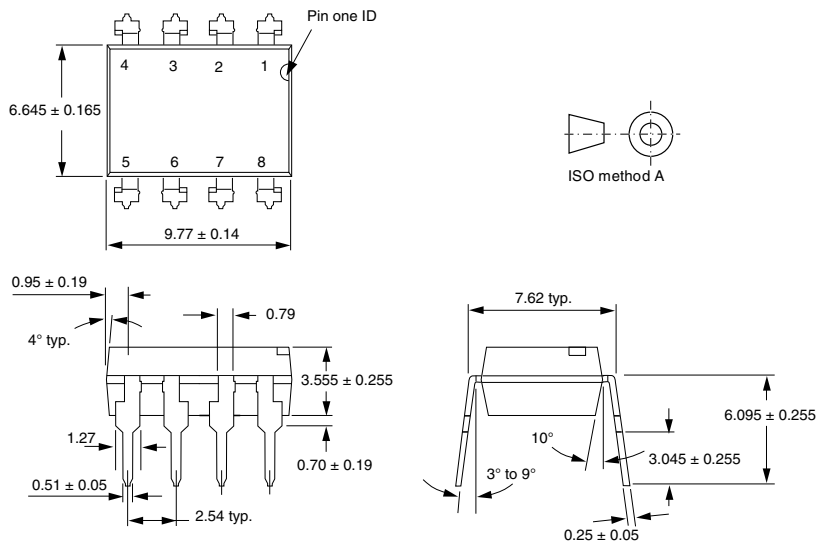


Fig. 16 - Maximum Detector Power Dissipation

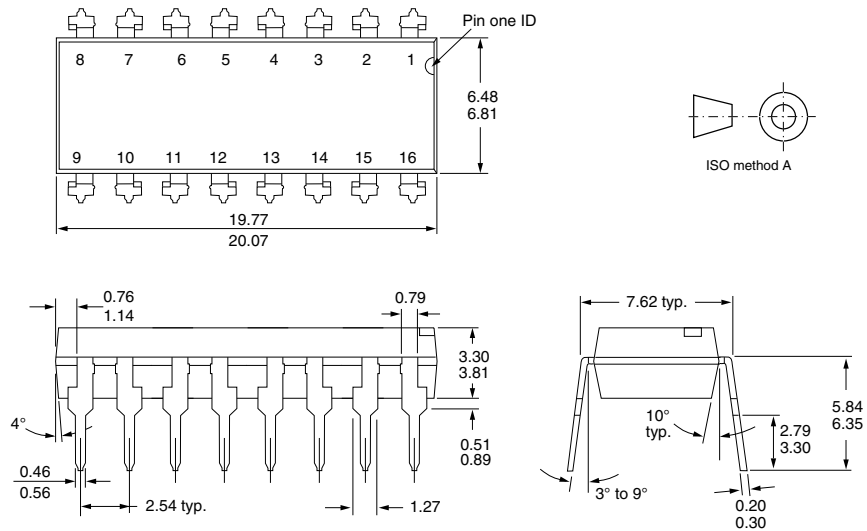
## PACKAGE DIMENSIONS in millimeters



# ILD620, ILD620GB, ILQ620, ILQ620GB

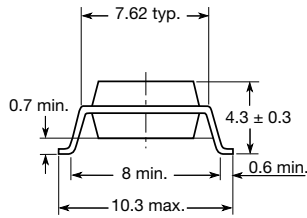


Vishay Semiconductors Optocoupler, Phototransistor Output,  
AC Input (Dual, Quad Channel)

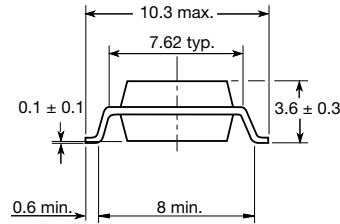


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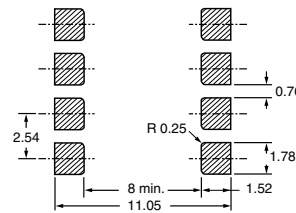
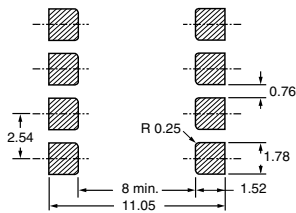
## Option 7



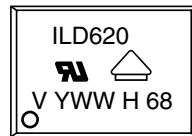
## Option 9



20802-16



## PACKAGE MARKING



21764-95





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